

Looking ahead, the production of new Ge diodes

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Looking ahead, the production of new Ge diodes



- Increase mass of ⁷⁶Ge (about 2^x)
 Decrease detector background
 → one order magnitude in total
- Minimize cosmogenic activation (production of ⁶⁸Ge and ⁶⁰Co long-lived isotopes into detector)
- New detector design (segmented and BEGe detectors)

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Enriched material for GERDA Phase II: **motivation**

The sensitivity $(T_{1/2}) \sim \delta(enr\%)/\delta(nat\%) =$ = (86%/7,61%) = 11

One ⁷⁶Ge diode \Rightarrow 11 ^{nat}Ge diodes



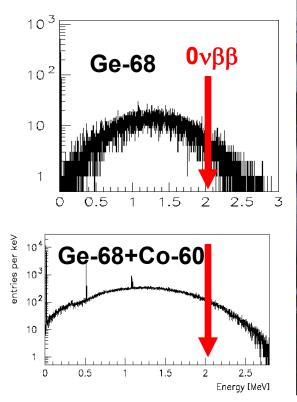
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Cosmic ray activation



Ge + N component → 60Co and 68Ge



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remary cosmic ray

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- Enrichment on Ge-76 \geq 86% (11 times \uparrow)
- Total quantity of ^{enr}Ge: 37,5 kg Cost effective industrial scale production: only gas-centrifuge separation
- To decrease Ge-68 and Co-60 production:
 Depletion of Ge-70 ≤ 0.01% (> 300 ↓)
 Minimization of exposure of ^{enr}Ge to cosmic rays at Earth surface
- Chemical purity to start HPGe detector production: 6N (99,9999%) electronic grade Ge metal



The ECP (Zelenogorsk, Russia): biggest in the world plant for production of stable isotopes by gas-centrifuge method



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Zelenogorsk (former Krasnoyarsk-45): the city on Green Mountains



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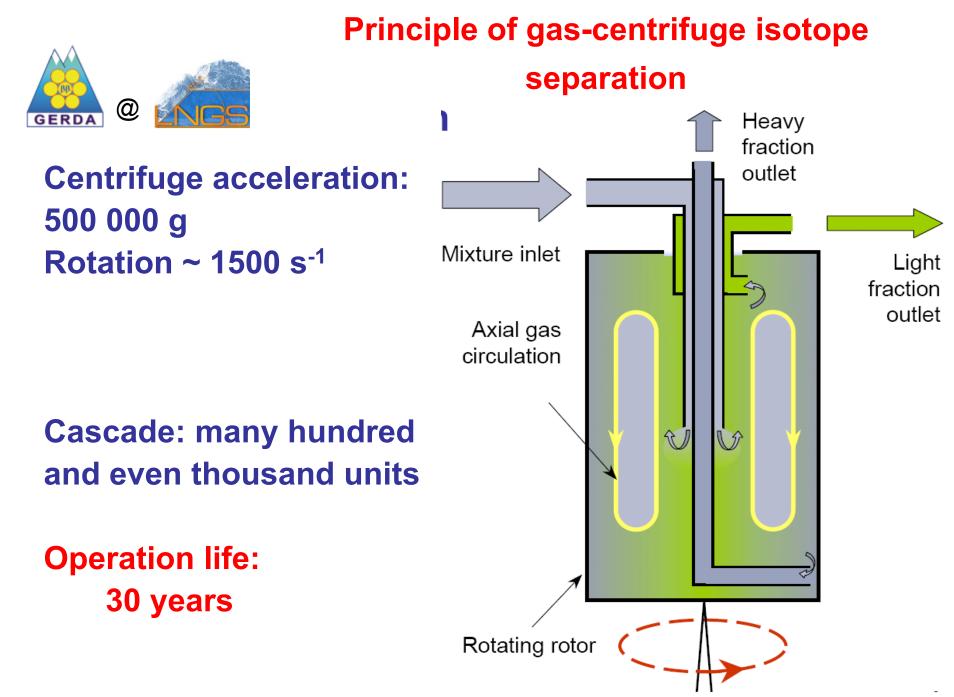
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Enrichment procedure at the ECP for GERDA Phase II



Fluorination: ^{nat}Ge (99,9999%) → ^{nat}GeF4



Isotopic separation: $^{nat}GeF_4 \rightarrow ^{76}GeF_4$ (13 kg \rightarrow 1kg) (~ 0,5 tons of 99,9999% Ge metal \rightarrow 37,5 kg)



Chemistry: ⁷⁶GeF₄ → ⁷⁶GeO₂ (99.8% - technical grade)

Storage at shallow depth (underground)

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Svetlana Department, ECP





Anatoly Shubin (1939 - 2008)





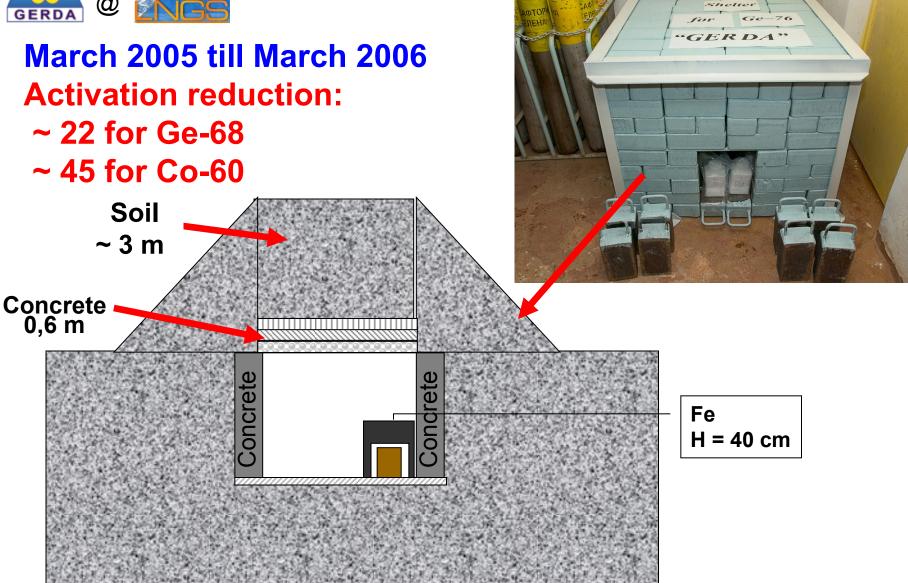


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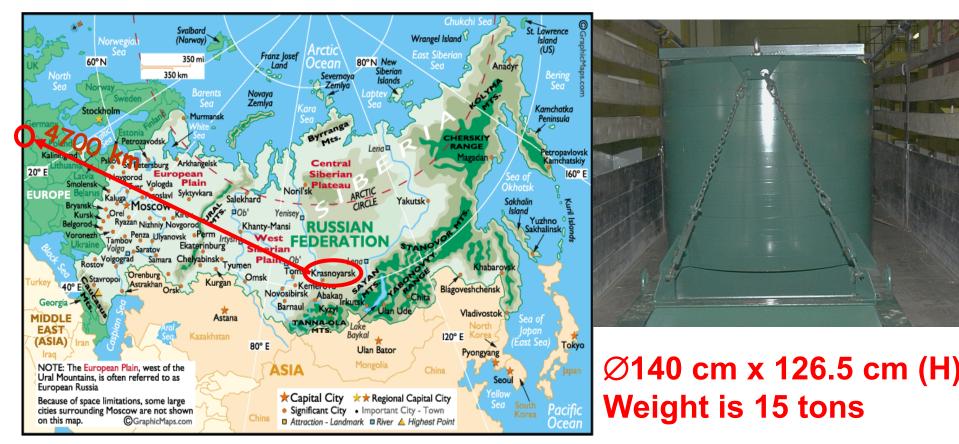
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Transportation: Zelenogorsk (Siberia) – Munich, 4700 km

Reduction of cosmic activation

K = 8 \downarrow for ⁶⁸Ge K = 13 \downarrow for ⁶⁰Co



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Transportation: Zelenogorsk (Siberia) – Munich, 4700 km

Possible question at customs:

just 54 kg of Ge oxide inside 15 tons ""pile of metal"?





Test Run first (15 kg of natGe): Feb. – March 2005

Run 2 (37,5 kg of 76Ge): GEMarichgApril@2006, 9.11.2010



Transport container arrived at MPP: Rally Zelenogorsk – Munich is over





⁷⁶Ge in Munich: celebration with VODKA®



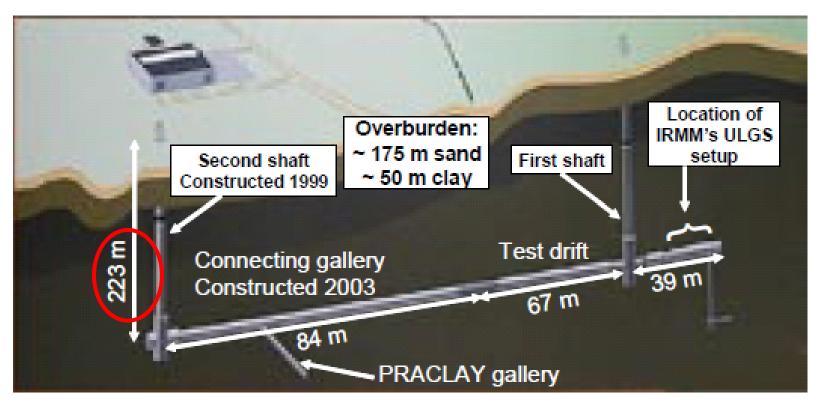
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HADES underground lab (Geel, Belgium): storage of ⁷⁶GeO₂ during 4 years

Arrival from Munich: 11 April 2006



Departure from Geel to the Rammelsberg mine in Goslar near PPM Pure Metals: 08 March 2010 $T_{exp} = 6$ hours

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Reduction and Purification of ^{enr}**Ge**

- Main issue: reduction ^{enr}GeO₂ to ^{enr}Ge metal and purification from 99,98% → 99,9999999% (10N) with no isotopic dilution...
- 2 years of R&D with depleted GeO₂ after enrichment process at various sites in Russia and Germany

2 batches of depGeO₂ powder (50 kg + 34 kg) that has the same properties and purity as enrGeO₂ were bought from ECP

- In 2009: we chose PPM Pure Metals (Germany) as industrial partner for reduction & purification
- In 2010: Reduction & purification of ^{enr}Ge (37,5 kg) was made



PPM Pure Metals (Langelsheim, Germany)









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Reduction & Purification at PPM Pure Metals (Langelsheim, Germany)



1) 50+34 = 84 kg of ^{dep}GeO₂ 2) 54 kg of ^{enr}GeO₂

Reduction

> 98% yield

Zone refinement (ZR) Yield ≻ 94%(^{enr}Ge)

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^{enr}Ge in form of metal bars

ZR: 37,2 kg → 35,45 kg purified + 1,161 kg (< 50 Ohm*cm)
➤Total exposure = 5,25 days, including transportation
>94% overall yield

Next steps depend on the detector technology we will choose



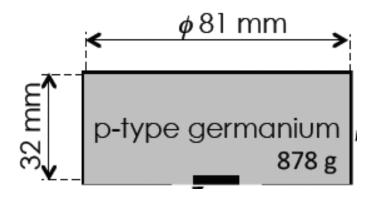
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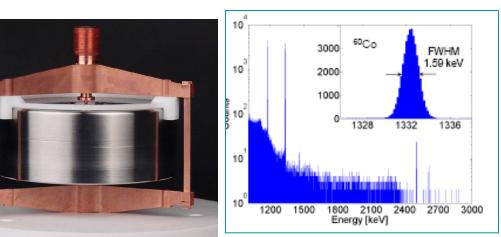
Two technologies of detector production: n-type segmented and p-type BEGe



n-type detectors with18-fold segmented electrodesm = 1.6 kg



Commercial p-type BEGe detectors with advanced $0\nu\beta\beta$ signal recognition & background suppression; **m = 0,9 kg**

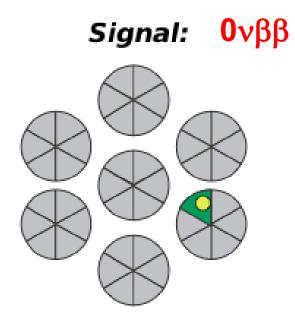


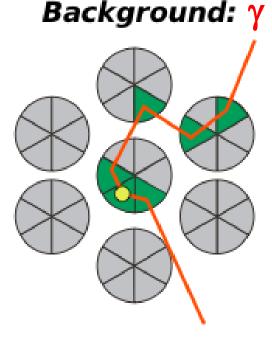
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Further background suppression in Phase II – segmented detector (1)





Single Site Event (SSE)

Multi Site Event (MSE)

Crystal and segment anti-coincidence possible

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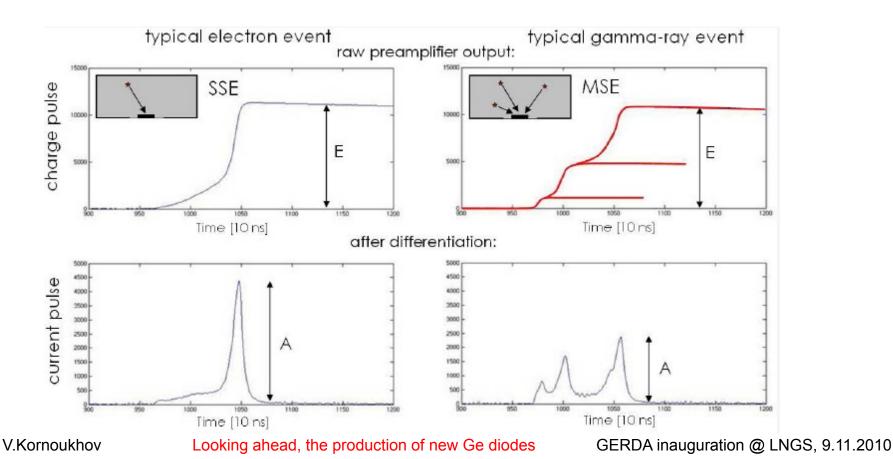


Further background suppression in Phase II – BEGe detector (2)

Pulse Shape Discrimination

0νββ







Crystal pulling and detector production for Phase II: status and future

n-type crystal

- No industrial manufacturer
- R&D with Leibniz-Institut für Kristallzüchtung (Berlin)

- purity of 12 N achieved (99,999999999%)
- still need to reduce impurities by one order of magnitude
- Canberra-Lingolsheim for detector manufacture

p-type crystal

 Since 2008, Canberra Oak Ridge and Canberra Olen as industrial partners. Industrial BEGe detector as nominal option for Phase II

- good quality crystals,
- and the detectors made of ^{dep}Ge tested as good as BEGe detectors from standard production

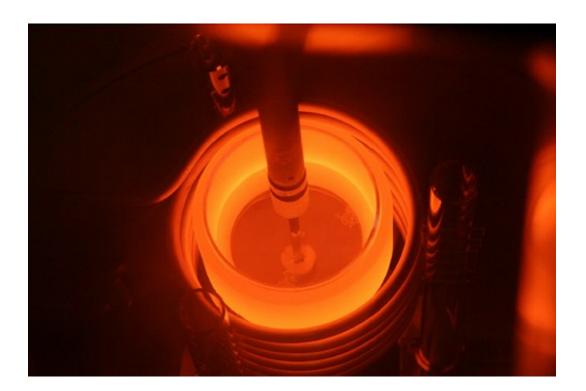
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Institut für Kristallzüchtung (IKZ, Berlin): crystal puller EKZ 2000

Crystal pulling (purity 99.999999999999 % Ge) some of the purest material in the world – impurities at the level of 10⁻¹²/atom





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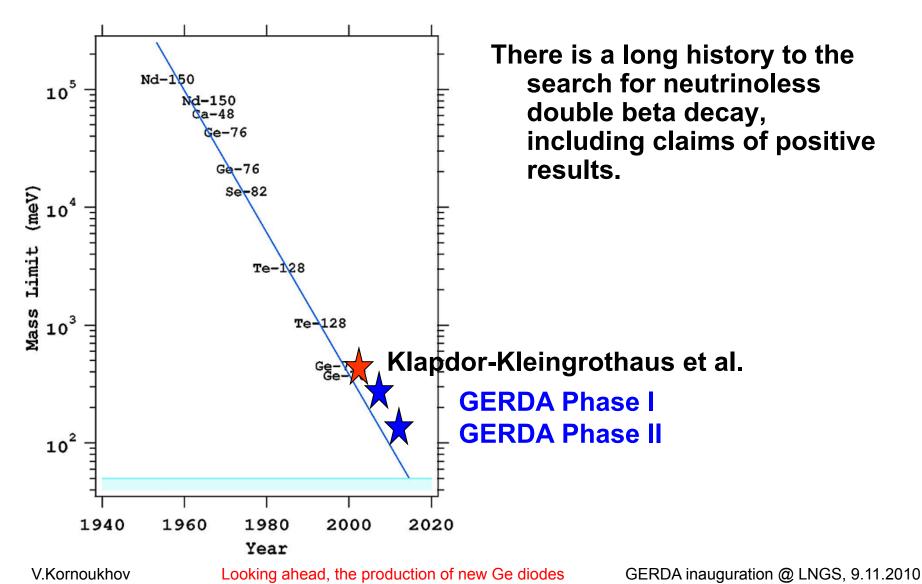


- Four crystal based on ^{dep}Ge were pulled by Canberra Oak Ridge and five detectors were produced by Canberra Olen.
- The detectors tested **as good as** BEGe detectors from standard production.
- Excellent performance both for energy resolution and background suppression via PSA.
- Expect first batch of Phase II enriched detectors the end of 2011 (early 2012)

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History and perspectives of Searches for 0νββ decay





Backup slides

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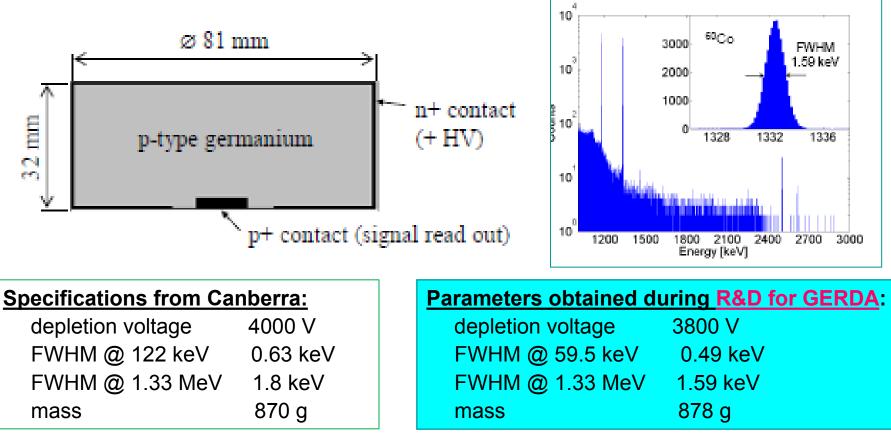
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Phase-II detector candidate # 2: BeGe (broad-energy) detector

modified model BE5030

the largest BEGe detector commercially available from Canberra Semiconductor, N.V. Olen

energy range 3 keV - 3 MeV enhanced efficiency for low-energy gammas low capacitance (\Rightarrow low noise)



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GERDA

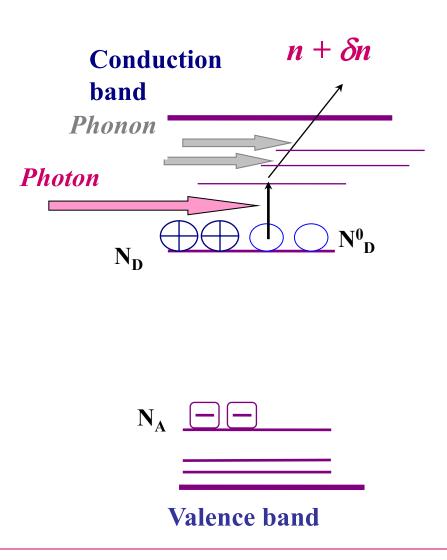
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- 1. Enrich in ⁷⁶Ge (>86%) (This step completed -37.5 kg in underground storage)
 - Suppression of internal backgrounds
 - Cost
 - Signal/background
- 2. Zone refining (purity 99.9999-99.99999999 % Ge)
- 4. Detector manufacture
- 5. In parallel development of support and cabling system

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